



GAU 2811 #6/Pe
5/11/99
T. Roots

PATENT
AMAT/2966/PDD/KPU1/JW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Rath, et al. §

Serial No.: 09/165,248 §

Filed: October 1, 1998 §

For: A Silicon Carbide Deposition For §
Use As A Barrier Layer and An §
Etch Stop §

Assistant Commissioner of Patents
Washington, D.C. 20231

Group Art Unit: 2811

Examiner: Unknown

CERTIFICATE OF MAILING 37 C.F.R. 1.8	
I hereby certify that this correspondence is being deposited on April 8, 1999, in the U. S. Postal Service as First Class Mail in an envelope addressed to: Assistant Commissioner of Patents, Washington, D. C. 20231.	
04/08/1999 Date	<u>D. Brit Nelson</u> D. Brit Nelson

Sir:

PRELIMINARY AMENDMENT

Prior to examination of the above referenced application, the Applicants request that the application be amended as follows:

In the specification:

Please change "Watts/cm²" references to "Watts/in²" at the following location:

Page 9, TABLE 1; row 8, column 1.

Please change all "cm²" references to "in²" at the following locations:

Page 10, lines 17 and 26; and

Page 13, lines 7 and 14.

In the claims:

Please change all "centimeter" references to "inch" at the following locations:

Claim 11, line 3;

Claim 13, line 6;

Claim 20, line 3;

Claim 21, line 7; and

Claim 27, line 7.

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